NSN 5961-01-576-8755

Diode Semiconductor Device - Page 1 of 1



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| Overall Length: |
|--|
| Between 3.7 millimeters and 3.9 millimeters |
| Overall Height: |
| 1.1 millimeters |
| Overall Width: |
| 1.6 millimeters |
| Function For Which Designed: |
| Zener diode |
| Mounting Method: |
| Terminal |
| Voltage Rating In Volts Per Characteristic: |
| 4.7 breakdown voltage, collector-to-base, emitter open nanoamperes |
| Power Rating Per Characteristic: |
| 500.0 milliwatts total power dissipation |
| Terminal Type And Quantity: |
| 2 bonding pad |
| Shelf Life: |
| N/a |
| Unit Of Measure: |
| |
| Demilitarization: |
| No |
| Fiig: |
| A110a0 |
| |
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